I hereby certify that this correspondence is being deposited with the U.S. Postal Service as Express Mal. Altrill No. EV32377141US, in an enyuetipe adjressed to: MS\_Non-Fee Amendment, Commissioner for Patients, P.O. Box (450, Aleyshindra, 222313-1450, on the date shown below. Date: September 16, 2003 Signature:

Docket No.: 30205/37980A

D3 Signature: (PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Seon Y. Cha

Application No.: Not Yet Assigned

Art Unit: Not Yet Assigned

Filed: March 25, 2002

Examiner: Not Yet Assigned

For: Magnetic Random Access Memory Having Transistor of Vertical Structure with Writing Line Formed on an Upper Portion of the Magnetic

Tunnel Junction Cell

## FIRST PRELIMINARY AMENDMENT

MS Non-Fee Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

## INTRODUCTORY COMMENTS

Prior to examination on the merits, please amend the above-identified U.S. patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks begin on page 4 of this paper.